

Peak Emission Wavelength: 880nm

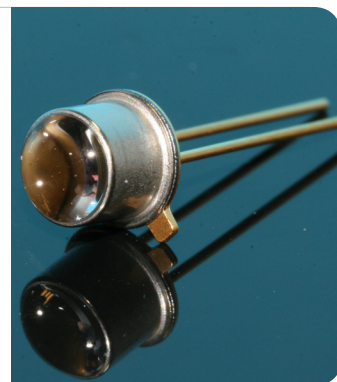
The 880nm IR emitter series is designed for applications requiring high output and precise optical / mechanical axis alignment. Custom package solutions and sorting are available.

FEATURES

- > Hermetically Sealed TO-46
- > High Output Power
- > Narrow Beam Angle
- > High Reliability

APPLICATIONS

- > Optical Switches / Security Systems
- > Linear & Rotary Encoder
- > Remote Controls / Robotics
- > Card Readers / Medical Electronics



Absolute Maximum Ratings (Ta=25°C)

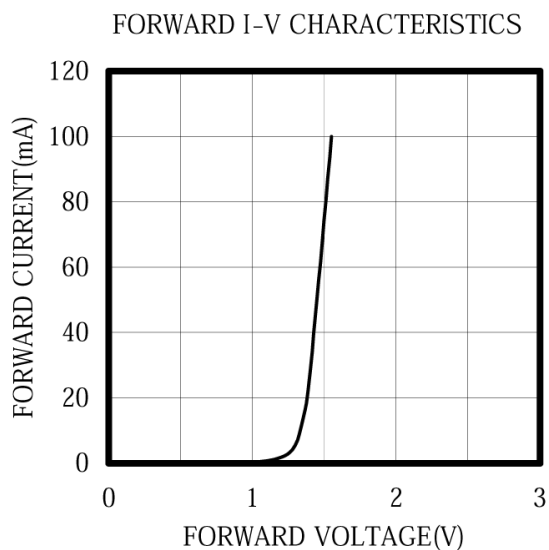
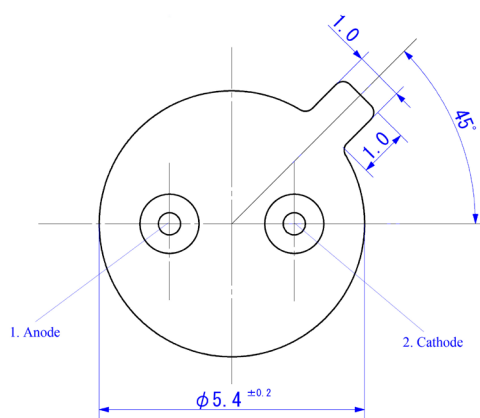
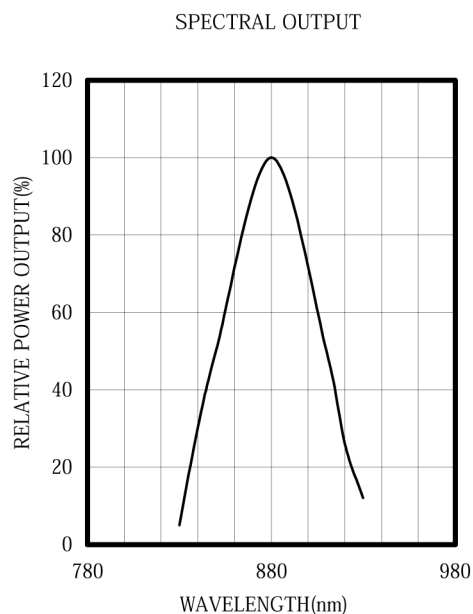
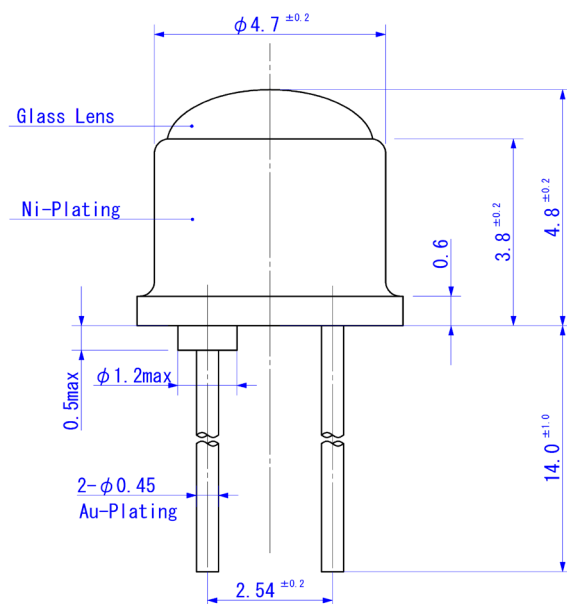


ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	1	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	180	mW
Operating Temperature Range	Topr	-30 ~ +100	°C
Storage Temperature Range	Tstg	-40 ~ +125	°C
Junction Temperature	Tj	125	°C
Lead Soldering Temperature*2	Tls	260	°C

*1: Tw=10μsec, T=10msec. *2: Time 5 Sec max, Position: Up to 3mm from the body.

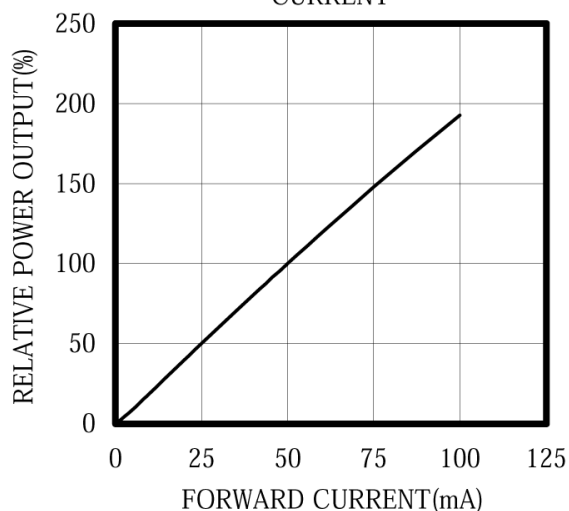
Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	2.4	4.0	--	mW
Forward Voltage	VF	IF=50mA	--	1.45	1.8	V
Reverse Current	IR	VR=5V	--	--	10	μA
Peak Emission Wavelength	λp	IF=50mA	860	880	--	nm
Spectral Line Half Width	Δλ	IF=50mA	--	60	--	nm
Half Intensity Beam Angle	Θ	IF=50mA	--	±4	--	deg
Rise Time	Tr	IFP=50mA	--	1.5	--	μS
Fall Time	Tf	IFP=50mA	--	0.8	--	μS
Junction Capacitance	Cj	1MHz, V=0V	--	15	--	pF
Temperature Coefficient of PO	P/T	IF=10mA	--	-0.5	--	%/°C
Temperature Coefficient of VF	V/T	IF=10mA	--	-1.5	--	mV/°C

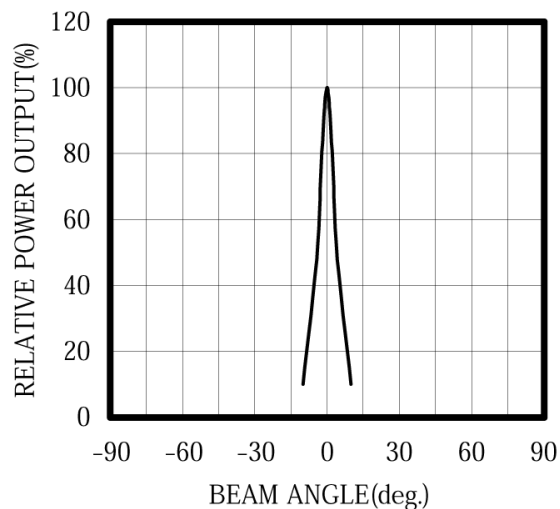


Unit: mm, Tolerance: ± 0.2

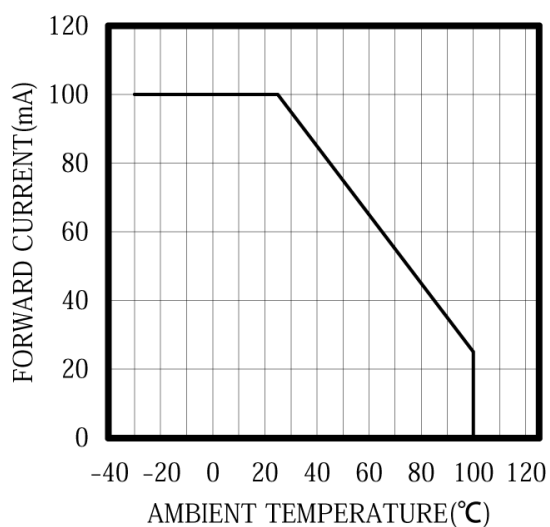
RELATIVE POWER vs FORWARD CURRENT



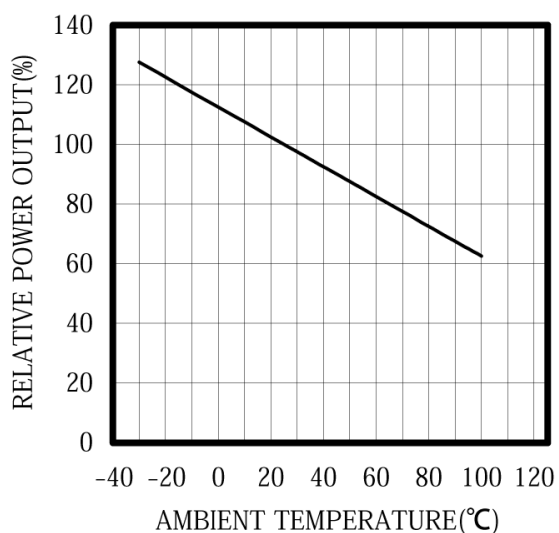
RADIATION PATTERN

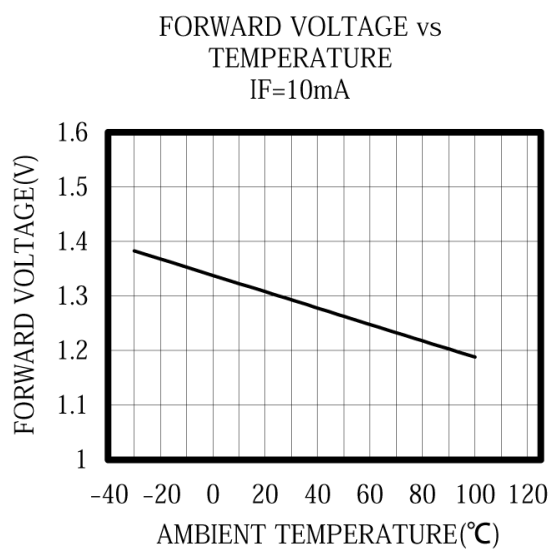


THERMAL DERATING CURVE



POWER OUTPUT vs TEMPERATURE
IF=10mA





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